#### 100 to 225 MHz Highpass; 150 to 450 MHz Lowpass

# Description

AM3090 is a miniature digitally tunable filter providing selectable highpass filtering over the 100 to 225 MHz and independently selectable lowpass filtering over the 150 to 450 MHz frequency range. The filter also provides a bypass mode where only the lowpass filter is active. With independent

4 bit digital control for each of the filters many center frequency/bandwidth configurations can easily be achieved. AM3090 has a compact 4mm x 8mm QFN footprint.

## Features

0

-10

-20

-30

-40

-50

-60 -70

-80 .01

S21 (dB)

- Independent LP and HP Control
- DC Coupled Lowpass Mode
- +3.3V to +5.0V Supply
- 4-bit Control, +3V to +5V Logic
- 3.0 dB Insertion Loss
- Integrated Control Line Filtering
- 4mm x 8mm QFN Package
- -40C to +85C Operation
- No Calibration Required

## **Characteristic Performance**

.1

Frequency (GHz)

Adjustable Center Frequency



10 20

0

-10

-20

-30

<sup>0)</sup> -40

-50 -60

-70 -80

.01

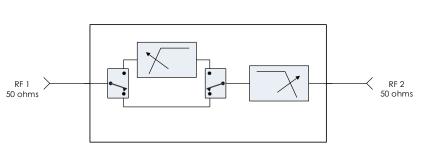
(dB)

.1

Frequency (GHz)

# DC-Coupled Low Pass Mode

10 20



**Functional Diagram** 







# 100 to 225 MHz Highpass; 150 to 450 MHz Lowpass

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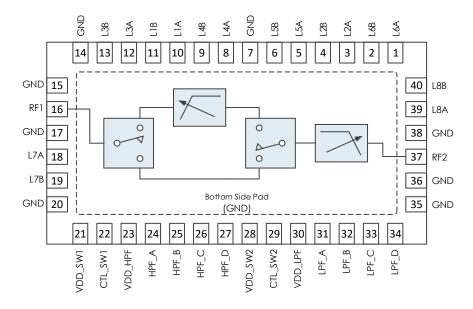
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## **Revision History**

Date	<b>Revision Number</b>	Notes
February 12, 2019	7	Updated to new datasheet format. Fixed pinout.
September 26, 2019	8	Corrected inductor part numbers in typical application circuit table.
October 17, 2023	9	MSL Corrected to MSL 3



# **Pin Layout and Definitions**

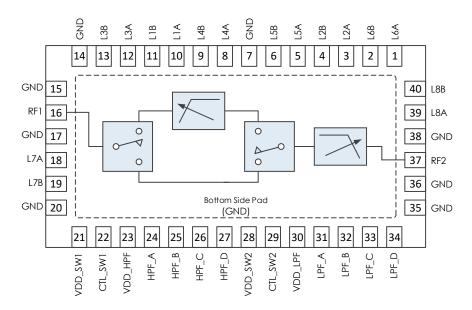


Pin Number	Pin Name	Pin Function		
1	L6A	External Inductor L6 Connection		
2	L6B	External Inductor L6 Connection		
3	L2A	External Inductor L2 Connection		
4	L2B	External Inductor L2 Connection		
5	L5A	External Inductor L5 Connection		
6	L5B	External Inductor L5 Connection		
7	GND	Ground – Common		
8	L4A	External Inductor L4 Connection		
9	L4B	External Inductor L4 Connection		
10	L1A	External Inductor L1 Connection		
11	L1B	External Inductor L1 Connection		
12	L3A	External Inductor L3 Connection		
13	L3B	External Inductor L3 Connection		
14, 15	GND	Ground – Common		
16	RF1	RF Port 1 – 50 Ohms – DC Coupled. External DC blocking		
17	GND	capacitor required Ground – Common		
18	L7A	External Inductor L7 Connection		
19	L7B	External Inductor L7 Connection		
20	GND	Ground – Common		
21	VDD_SW1	DC Power Input		
22	CTL SW1	Control Line for Switch 1		



100 to 225 MHz Highpass; 150 to 450 MHz Lowpass

## **Pin Layout and Definitions**



Pin Number	Pin Name	Pin Function		
23	VDD_HPF	DC Power Input		
24	HPF_A	Highpass Filter Control Bit A		
25	HPF_B	Highpass Filter Control Bit B		
26	HPF_C	Highpass Filter Control Bit C		
27	HPF_D	Highpass Filter Control Bit D		
28	VDD_SW2	DC Power Input		
29	CTL_SW2	Control Line for Switch 2		
30	VDD_LPF	DC Power Input		
31	LPF_A	Lowpass Filter Control Bit A		
32	LPF_B	Lowpass Filter Control Bit B		
33	LPF_C	Lowpass Filter Control Bit C		
34	LPF_D	Lowpass Filter Control Bit D		
35, 36	GND	Ground – Common		
37	RF2	RF Port 2 – 50 Ohms – DC Coupled. External DC blocking		
		capacitor required.		
38	GND	Ground – Common		
39	L8A	External Inductor L8 Connection		
40	L8B	External Inductor L8 Connection		
Bottom Pad	GND	Ground – Common		



## 100 10 223 Mill2 Highpuss, 100 10 400

# **Specifications**

#### **Absolute Maximum Ratings**

	Minimum	Maximum
Supply Voltage	-0.3 V	+6.0 V
RF Input Power		+27 dBm
Operating Junction Temperature	-40 C	+150 C
Storage Temperature Range	-50 C	+150 C

**Note:** Any device operation beyond the Absolute Maximum Ratings may result in permanent damage to the device. The values listed in this table are extremes and do not imply functional operation of the device at these or any other conditions beyond what is listed under Recommended Operating Conditions. Any part subjected to conditions outside of what is recommended for an extended amount of time may suffer from reliability concerns.

#### **Handling Information**

	Minimum	Maximum
Storage Temperature Range (Recommended)	-50 C	+125 C
Moisture Sensitivity Level	MSL 3	



Atlanta Micro products are electrostatic sensitive.

Follow safe handling practices to avoid damage

#### **Recommended Operating Conditions**

	Minimum	Typical	Maximum
Supply Voltage	+3.0 V	+5.0 V	+5.2 V
Operating Case Temperature	-40 C		+85 C
Operating Junction Temperature	-40 C		+125 C



#### **DC Electrical Characteristics**

(T = 25 °C unless otherwise specified)

Parameter	<b>Testing Conditions</b>	Minimum	Typical	Maximum
DC Supply Voltage		+3.0 V	+5.0 V	+5.2 V
DC Supply Current	VDD = +5.0 V		3 mA	
Power Dissipated	VDD = +5.0 V		15 mW	
Logic Level Low		-0.1 V		+0.5 V
Logic Level High		+2.0 V		+5.0 V

#### **RF Performance**

(T = 25 °C unless otherwise specified)

Parameter	<b>Testing Conditions</b>	Minimum	Typical	Maximum
HPF Frequency Range		100 MHz		225 MHz
LPF Frequency Range		150 MHz		450 MHz
Insertion Loss			3 dB	
Input IP3	f = 350 MHz		+40 dBm	

#### **Timing Characteristics**

Parameter	Minimum	Typical	Maximum
Switching Speed		1µs	

#### State Tables

SW1	SW2	State
Low	High	HPF Bypassed
High	Low	HPF Active



100 to 225 MHz Highpass; 150 to 450 MHz Lowpass

# State Tables (continued)

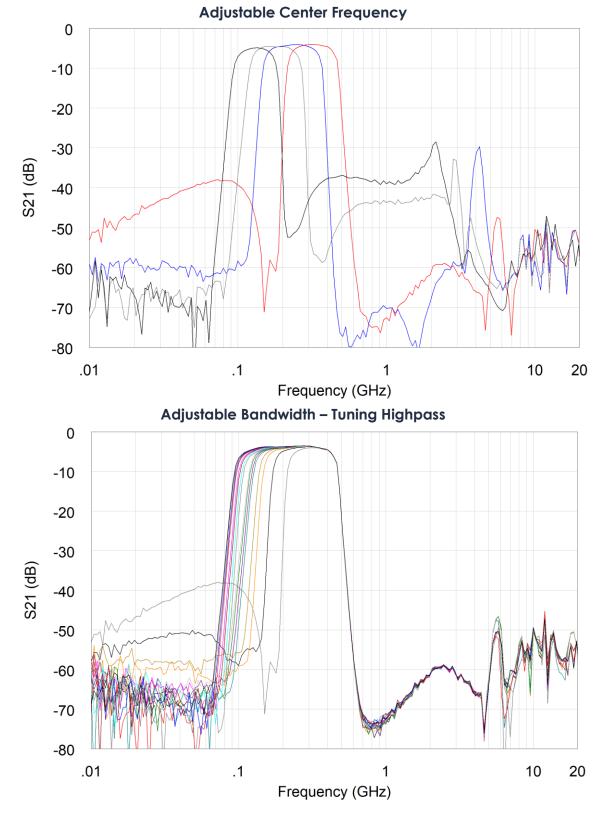
High Pass Control Lines				Typical Cutoff
HPF_D	HPF_C	HPF_B	HPF_A	Frequency (MHz)
L	L	L	L	102
L	L	L	Н	103
L	L	Н	L	105
L	L	Н	Н	106
L	Н	L	L	110
L	Н	L	Н	112
L	Н	Н	L	116
L	Н	Н	Н	120
Н	L	L	L	127
Н	L	L	Н	130
Н	L	Н	L	134
Н	L	Н	Н	138
Н	Н	L	L	148
Н	Н	L	Н	159
Н	Н	Н	L	183
Н	Н	Н	Н	228

Low Pass Control Lines				Typical Cutoff
LPF_D	LPF_C	LPF_B	LPF_A	Frequency (MHz)
L	L	L	L	153
L	L	L	Н	156
L	L	Н	L	162
L	L	Н	Н	165
L	Н	L	L	172
L	Н	L	Н	177
L	Н	Н	L	185
L	Н	Н	Н	190
Н	L	L	L	215
Н	L	L	Н	226
Н	L	Н	L	246
Н	L	Н	Н	264
Н	Н	L	L	309
Н	Н	L	Н	333
Н	Н	Н	L	385
Н	Н	Н	Н	450



100 to 225 MHz Highpass; 150 to 450 MHz Lowpass

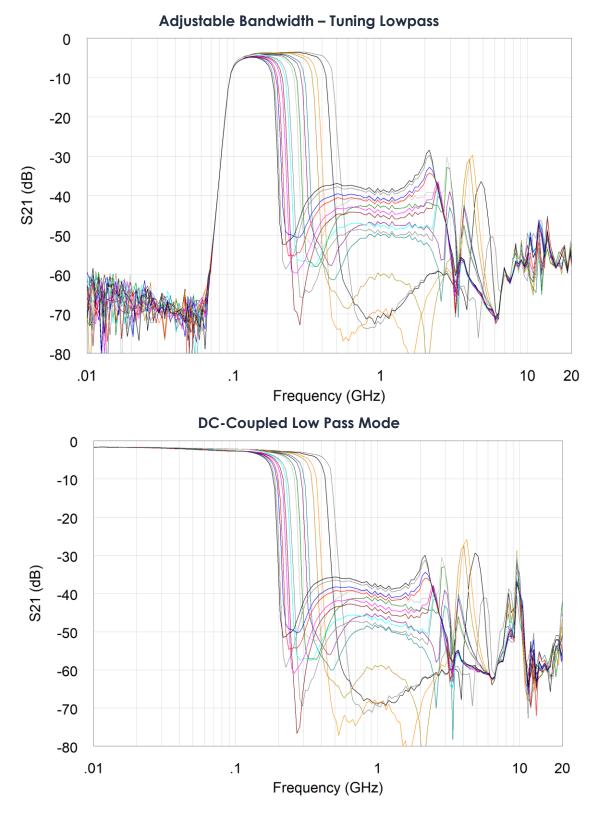
#### **Typical Performance**





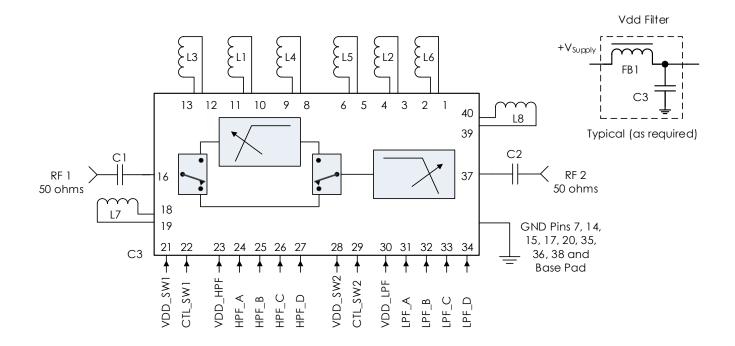
## 100 to 225 MHz Highpass; 150 to 450 MHz Lowpass

#### Typical Performance (continued)





# **Typical Application**



#### Recommended Component List (or equivalent):

Part	Value	Part Number	Manufacturer
C1, C2	0.1 µF	0402BB104KW160	Passives Plus
C3	0.1 µF	C1005X7R1H104K050BB	TDK
FB1	-	MMZ1005A222E	TDK
L4, L7	68 nH	0402HP-68NXGLW	Coilcraft
L1, L3	56 nH	0402HP-56NXGLW	Coilcraft
L2, L6	27 nH	0402HP-27NXGLW	Coilcraft
L5, L8	24 nH	0402HP-24NXGLW	Coilcraft

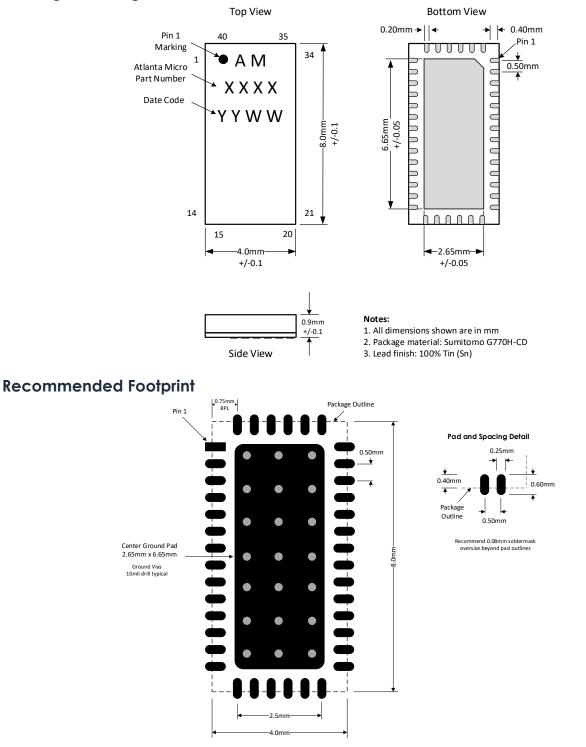
#### Notes:

- 1. DC blocking capacitors should be low-loss, broadband capacitors for optimum performance
- 2. Routes to off-chip inductors, L1 through L8, should be kept as short as possible.
- 3. VDD and control lines filtered internally providing high frequency isolation to 50 + GHz.



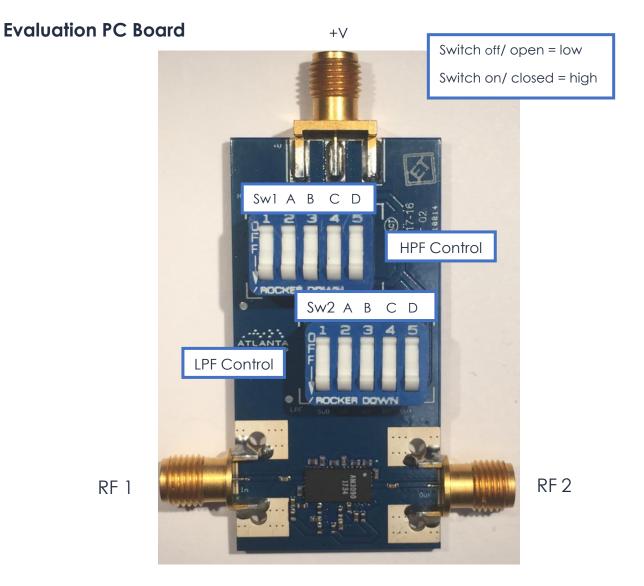
# **Package Details**

#### **Package Drawing**





100 to 225 MHz Highpass; 150 to 450 MHz Lowpass



# **Related Parts**

Part Number				Description
AM3060	400 MHz	to	6.5 GHz	Switched Digitally Tunable BPF Bank
AM3063	6.0 GHz	to	18.0 GHz	Digitally Tunable Bandpass Filter Bank
AM3064	1.0 GHz	to	6.5 GHz	Digitally Tunable Bandpass Filter Bank
AM3065	6.0 GHz	to	12.0 GHz	Digitally Tunable Bandpass Filter
AM3066	12.0 GHz	to	26.5 GHz	Digitally Tunable Bandpass Filter Bank
AM3102	330 MHz	to	1.2 GHz	Digitally Tunable Bandpass Filter
AM3103	1.0 GHz	to	3.0 GHz	Digitally Tunable Bandpass Filter
AM3104	2.5 GHz	to	6.5 GHz	Digitally Tunable Bandpass Filter



## **Component Compliance Information**

**RoHS:** Atlanta Micro, Inc. hereby certifies that all products comply with the EC Directive 2011/65/EC on the Restriction of Hazardous Substances, commonly known as RoHS II. All products supplied by Atlanta Micro shall be compliant with the European Directive 2011/65/EC based on the following substance list.

Substance List	Allowable Maximum Concentration
Lead (Pb)	<1000 PPM (0.1% by weight)
Mercury (Hg)	<1000 PPM (0.1% by weight)
Cadmium (Cd)	<75 PPM (0.0075% by weight)
Hexavalent Chromium (CrVI)	<1000 PPM (0.1% by weight)
Polybrominated Biphenyls (PBB)	<1000 PPM (0.1% by weight)
Polybrominated Diphenyl ethers (PBDE)	<1000 PPM (0.1% by weight)
Decabromodiphenyl Deca BDE	<1000 PPM (0.1% by weight)

**REACH:** Atlanta Micro, Inc. neither uses nor intentionally adds any of the substances considered to be a Substance of Very High Concern (SVHC) as defined by the EU Regulation (EC) No. 1907-2006 on Registration, Evaluation, Authorization, and Restriction of Chemicals (REACH).

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